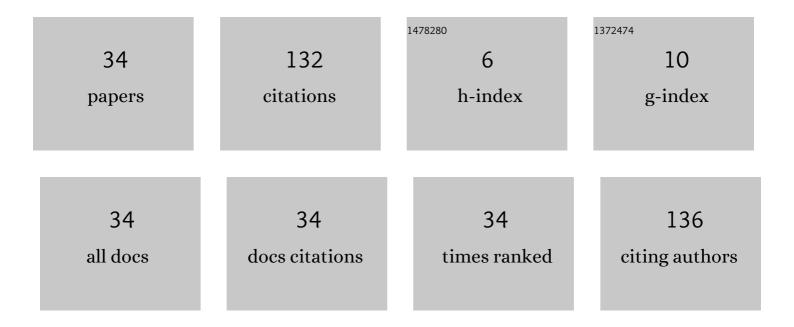
Ohsung Song

List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Effects of halide stripping with ferric ions and hydrogen peroxide oxidants for 18K gold alloys. Transactions of the Institute of Metal Finishing, 2021, 99, 121-125.	0.6	1
2	Properties of foamed glass upon addition of polysiloxane. Journal of Asian Ceramic Societies, 2020, 8, 930-938.	1.0	5
3	Properties of basalt-fiber reinforced foam glass. Journal of Asian Ceramic Societies, 2020, 8, 170-175.	1.0	7
4	Properties of foamed glass upon addition of nanocarbon and sintering temperatures. Journal of Asian Ceramic Societies, 2020, 8, 123-129.	1.0	5
5	Properties of Polysiloxane Coated Borosilicate Lining Blocks. Journal of the Korean Ceramic Society, 2017, 54, 525-529.	1.1	3
6	Properties of a Ru/Ti bilayered counter electrode in dye sensitized solar cells. Electronic Materials Letters, 2014, 10, 271-273.	1.0	3
7	Formation of ruthenium-dots on counter electrodes for dye sensitized solar cells. Electronic Materials Letters, 2014, 10, 263-266.	1.0	7
8	Properties of an Au/Pt bilayered counter electrode in dye sensitized solar cells. Electronic Materials Letters, 2014, 10, 981-984.	1.0	14
9	Properties of the nano-thick Pt/W bilayered catalytic layer employed dye sensitized solar cells. Electronic Materials Letters, 2014, 10, 627-630.	1.0	2
10	Properties of the Nano-Thick Al/Pt or Ti/Pt Bilayered Catalytic Layer Used in Dye Sensitized Solar Cells. Journal of Korean Institute of Metals and Materials, 2014, 52, 61-65.	0.4	5
11	Properties of the Natural and CVD Synthetic Diamonds for Identification. Journal of the Korean Ceramic Society, 2014, 51, 350-356.	1.1	1
12	lridium catalyst based counter electrodes for dye-sensitized solar cells. Current Applied Physics, 2013, 13, 1620-1624.	1.1	10
13	Property of Palladium Counter Electrode for Dye Sensitized Solar Cells. Journal of Korean Institute of Metals and Materials, 2013, 51, 071-076.	0.4	8
14	Effect of the thickness of the Ru-coating on a counter electrode on the performance of a dye-sensitized solar cell. Metals and Materials International, 2012, 18, 105-108.	1.8	15
15	Property of Counter Electrode with Pt and Ru Catalyst Films for Dye-Sensitized Solar Cell. Journal of Korean Institute of Metals and Materials, 2012, 50, 243-247.	0.4	6
16	Study on Self-Organized Ru Dots Using ALD and Low Temperature Rapid Thermal Annealing Process. Journal of Korean Institute of Metals and Materials, 2012, 50, 557-562.	0.4	2
17	Identification for the Vivid Yellow Diamonds. Journal of the Korean Ceramic Society, 2012, 49, 493-497.	1.1	0

18 MWCNT employed counter electrode for DSSCs. , 2011, , .

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#	Article	IF	CITATIONS
19	High resolution TEM and 3D imaging of hybrid polymer solar cell structures. , 2011, , .		Ο
20	Current stressing effects on the reliability of Cu pillar bump with shallow solder. , 2010, , .		0
21	Microstructure evolution of the Ir-inserted Ni silicides with additional annealing. Metals and Materials International, 2009, 15, 69-76.	1.8	Ο
22	Characterization of NiCo composite silicides by 10 nm-Ni50Co50 alloy films with additional annealing. Metals and Materials International, 2009, 15, 285-291.	1.8	2
23	Properties of iridium-inserted nickel silicides by thermal annealing of the Ni/Ir bilayer on silicon and polysilicon substrates. Metals and Materials International, 2007, 13, 229-234.	1.8	3
24	Properties of nickel-cobalt composite silicides by thermal annealing of Ni1â^'xCox (x=0.2, 0.5, and 0.8) alloy thin films on silicon and polysilicon substrates. Metals and Materials International, 2007, 13, 239-247.	1.8	1
25	Characterization of synthesized and treated gem diamonds. Metals and Materials International, 2007, 13, 427-431.	1.8	4
26	Property of cobalt nickel silicide by thermal annealing of Co/Ni bilayer on a silicon substrate. Metals and Materials International, 2006, 12, 189-192.	1.8	2
27	Formation of NiCoSix silicide by thermal annealing of Ni/Co bilayer on Si substrate. Materials Science in Semiconductor Processing, 2005, 8, 608-612.	1.9	13
28	Direct bonding of silicon paris with heterogeneous insulator using different annealing methods. Metals and Materials International, 2004, 10, 107-111.	1.8	1
29	Tunnel magnetoresistance with plasma oxidation time in doubly oxidized barrier process. Metals and Materials International, 2003, 9, 421-425.	1.8	0
30	Effect of inductively coupled plasma oxidation on properties of magnetic tunnel junctions. Journal of Applied Physics, 2003, 93, 1146-1149.	1.1	4
31	Spin dependent Transport Properties in Ferromagnetic Double Barrier Junctions Journal of the Magnetics Society of Japan, 2001, 25, 763-766.	0.4	0
32	Reduction of Resistance and Annealing Effect in Ferromagnetic Tunnel Junctions Journal of the Magnetics Society of Japan, 2000, 24, 591-594.	0.4	4
33	Tunnel Magnetoresistance Effect for Ni80Fe20/Co/N(N=Ta,Cu,Al)/Al-Oxide/Co Junctions Journal of the Magnetics Society of Japan, 2000, 24, 599-602.	0.4	2
34	Magnon Excitation at the Interface of Co/Al/Al-Oxide/Co Tunnel Junctions Journal of the Magnetics Society of Japan, 2000, 24, 615-618.	0.4	1